=> d his

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L1        13397  S  MEMORY AND FLASH
L2          133  S  L1 AND LOGICAL ADDRESS
L3           83  S  L2 AND PHYSICAL ADDRESS
L4           58  S  L3 AND ERAS?
L5           44  S  L4 AND SECTOR?
L6           58  S  L4 AND CONTROL?
L7           58  S  L6 AND WRIT?
L8           55  S  L7 AND REFERENCE?
L9           15  S  L8 AND ADDRESS(W)CONVER?
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